# Analog Switch, Dual SPDT, Ultra-Low 0.5 $\Omega$

The NLAS5223 is an advanced CMOS analog switch fabricated in Sub-micron silicon gate CMOS technology. The device is a dual Independent Single Pole Double Throw (SPDT) switch featuring Ultra–Low R<sub>ON</sub> of 0.5  $\Omega$ , at V<sub>CC</sub> = 3.0  $\pm$  0.3 V.

The part also features guaranteed Break Before Make (BBM) switching, assuring the switches never short the driver.

## Features

- Ultra–Low R<sub>ON</sub>,  $< 0.5 \Omega$  at V<sub>CC</sub> = 3.0  $\pm$  0.3 V
- NLAS5223 Interfaces with 2.8 V Chipset
- NLAS5223L Interfaces with 1.8 V Chipset
- Single Supply Operation from 1.65–3.6 V
- Smallest 1.4 x 1.8 x 0.75 mm Thin QFN Package
- Full 0–V<sub>CC</sub> Signal Handling Capability
- High Off-Channel Isolation
- Low Standby Current, < 50 nA
- Low Distortion
- $R_{ON}$  Flatness of 0.15  $\Omega$
- High Continuous Current Capability ± 300 mA Through Each Switch
- Large Current Clamping Diodes at Analog Inputs ± 100 mA Continuous Current Capability
- ESD Human Body Model > 2000 V
- These are Pb–Free Devices

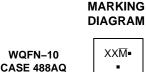
## Applications

- Cell Phone Audio Block
- Speaker and Earphone Switching
- Ring–Tone Chip / Amplifier Switching
- Modems



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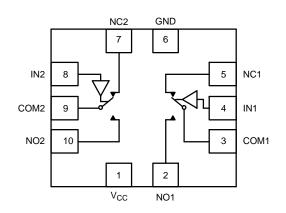
AU = NLAS5223AV = NLAS5223L

= Date Code

= Pb-Free Device

(Note: Microdot may be in either location)

= Specific Device Code



## **FUNCTION TABLE**

IN 1, 2	NO 1, 2	NC 1, 2
0	OFF	ON
1	ON	OFF

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

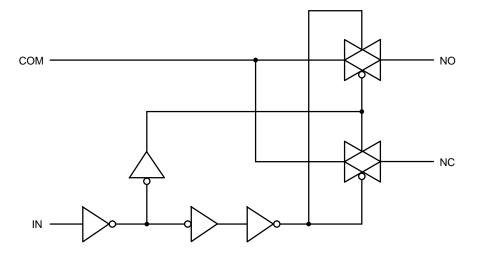


Figure 1. Logic Equivalent Circuit

#### **PIN DESCRIPTION**

QFN PIN #	Symbol	Name and Function
2, 5, 7, 10	NC1 to NC2, NO1 to NO2	Independent Channels
4, 8	IN1 and IN2	Controls
3, 9	COM1 and COM2	Common Channels
6	GND	Ground (V)
1	V <sub>CC</sub>	Positive Supply Voltage

## MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	-0.5 to +4.6	V
V <sub>IS</sub>	Analog Input Voltage (V <sub>NO</sub> , V <sub>NC</sub> , or V <sub>COM</sub> )	$-0.5 \le V_{IS} \le V_{CC} + 0.5$	V
V <sub>IN</sub>	Digital Select Input Voltage	$-0.5 \le V_{IN} \le +4.6$	V
I <sub>anl1</sub>	Continuous DC Current from COM to NC/NO	±300	mA
I <sub>anl-pk1</sub>	Peak Current from COM to NC/NO, 10 Duty Cycle (Note 1)	±500	mA
I <sub>cImp</sub>	Continuous DC Current into COM/NO/NC with Respect to $V_{CC}$ or GND	±100	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Defined as 10% ON, 90% OFF Duty Cycle.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parame	eter	Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage		1.65	3.6	V
V <sub>IN</sub>	Digital Select Input Voltage (OVT) Overvoltage Tolerance		GND	3.6	V
V <sub>IS</sub>	Analog Input Voltage (NC, NO, COM)		GND	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature Range		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Time, SELECT	V <sub>CC</sub> = 1.6 V – 2.7 V V <sub>CC</sub> = 3.0 V – 3.6 V		20 10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## NLAS5223 DC CHARACTERISTICS – DIGITAL SECTION (Voltages Referenced to GND)

				Guaranteed Limit		
Symbol	Parameter	Condition	v <sub>cc</sub>	25°C	–40°C to +85°C	Unit
V <sub>IH</sub>	Minimum High-Level Input Voltage, Select Inputs		3.0 3.6	1.4 1.7	1.4 1.7	V
V <sub>IL</sub>	Maximum Low–Level Input Voltage, Select Inputs		3.0 3.6	0.7 0.8	0.7 0.8	V
I <sub>IN</sub>	Maximum Input Leakage Current, Select Inputs	V <sub>IN</sub> = 3.6 V or GND	3.6	±0.1	±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	$V_{IN} = 3.6 V \text{ or GND}$	0	±0.5	±2.0	μΑ
I <sub>CC</sub>	Maximum Quiescent Supply Current (Note 2)	Select and $V_{IS} = V_{CC}$ or GND	1.65 to 3.6	±1.0	±2.0	μΑ

2. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

## NLAS5223 DC ELECTRICAL CHARACTERISTICS - ANALOG SECTION

				Gua	ranteed	l Maximur	n Limit	
				25	°C	-40°C t	o +85°C	
Symbol	Parameter	Condition	V <sub>CC</sub>	Min	Max	Min	Max	Unit
R <sub>ON</sub>	NC/NO On–Resistance (Note 3)		3.0 3.6		0.3 0.3		0.4 0.4	Ω
R <sub>FLAT</sub>	NC/NO On–Resistance Flatness (Notes 3 and 4)	$I_{COM} = 100 \text{ mA}$ $V_{IS} = 0 \text{ to } V_{CC}$	3.0 3.6		0.15 0.15		0.15 0.15	Ω
$\Delta R_{ON}$	On–Resistance Match Between Channels (Notes 3 and 5)	$V_{IS} = 1.5 V; \\ I_{COM} = 100 \text{ mA} \\ V_{IS} = 1.8 V; \\ I_{COM} = 100 \text{ mA} \end{cases}$	3.0 3.6		0.05 0.05		0.05 0.05	Ω
I <sub>NC(OFF)</sub> I <sub>NO(OFF)</sub>	NC or NO Off Leakage Current (Note 3)	$ \begin{array}{l} V_{IN} = V_{IL} \text{ or } V_{IH} \\ V_{NO} \text{ or } V_{NC} = 0.3 \ V \\ V_{COM} = \ 3.3 \ V \end{array} $	3.6	-10	10	-100	100	nA
I <sub>COM(ON)</sub>	COM ON Leakage Current (Note 3)	$\begin{array}{l} V_{IN} = V_{IL} \mbox{ or } V_{IH} \\ V_{NO} \mbox{ 0.3 V or } 3.3 \mbox{ V with} \\ V_{NC} \mbox{ floating or} \\ V_{NC} \mbox{ 0.3 V or } 3.3 \mbox{ V with} \\ V_{NO} \mbox{ floating} \\ V_{COM} = 0.3 \mbox{ V or } 3.3 \mbox{ V} \end{array}$	3.6	-10	10	-100	100	nA

3. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

4. Flatness is defined as the difference between the maximum and minimum value of On-resistance as measured over the specified analog signal ranges.

5.  $\Delta \breve{R}_{ON} = \breve{R}_{ON(MAX)} - R_{ON(MIN)}$  between NC1 and NC2 or between NO1 and NO2.

#### NLAS5223L DC CHARACTERISTICS – DIGITAL SECTION (Voltages Referenced to GND)

				Guaranteed Limit		
Symbol	Parameter	Condition	V <sub>cc</sub>	25°C	–40°C to +85°C	Unit
V <sub>IH</sub>	Minimum High-Level Input Voltage, Select Inputs		3.0 3.6	1.1 1.3	1.1 1.3	V
V <sub>IL</sub>	Maximum Low–Level Input Voltage, Select Inputs		3.0 3.6	0.5 0.5	0.5 0.5	V
I <sub>IN</sub>	Maximum Input Leakage Current, Select Inputs	V <sub>IN</sub> = 3.6 V or GND	3.6	±0.1	±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	$V_{IN} = 3.6 V \text{ or GND}$	0	±0.5	±2.0	μΑ
I <sub>CC</sub>	Maximum Quiescent Supply Current (Note 6)	Select and $V_{IS} = V_{CC}$ or GND	1.65 to 3.6	±1.0	±2.0	μΑ

6. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

## NLAS5223L DC ELECTRICAL CHARACTERISTICS – ANALOG SECTION

				Gua	ranteed	l Maximur	n Limit	
				25	i∘C	-40°C t	o +85°C	
Symbol	Parameter	Condition	V <sub>CC</sub>	Min	Мах	Min	Max	Unit
R <sub>ON</sub>	NC/NO On–Resistance (Note 7)		3.0 3.6		0.3 0.3		0.4 0.4	Ω
R <sub>FLAT</sub>	NC/NO On–Resistance Flatness (Notes 7 and 8)	$I_{COM} = 100 \text{ mA}$ $V_{IS} = 0 \text{ to } V_{CC}$	3.0 3.6		0.15 0.15		0.15 0.15	Ω
$\Delta R_{ON}$	On-Resistance Match Between Channels (Notes 7 and 9)	$V_{IS} = 1.5 V; \\ I_{COM} = 100 \text{ mA} \\ V_{IS} = 1.8 V; \\ I_{COM} = 100 \text{ mA} \end{cases}$	3.0 3.6		0.05 0.05		0.05 0.05	Ω
I <sub>NC(OFF)</sub> I <sub>NO(OFF)</sub>	NC or NO Off Leakage Current (Note 7)	$ \begin{array}{l} V_{IN} = V_{IL} \text{ or } V_{IH} \\ V_{NO} \text{ or } V_{NC} = 0.3 \ V \\ V_{COM} = \ 3.3 \ V \end{array} $	3.6	-10	10	-100	100	nA
I <sub>COM(ON)</sub>	COM ON Leakage Current (Note 7)	$ \begin{array}{l} V_{IN} = V_{IL} \mbox{ or } V_{IH} \\ V_{NO} \mbox{ 0.3 V or } 3.3 \mbox{ V with} \\ V_{NC} \mbox{ floating or} \\ V_{NC} \mbox{ 0.3 V or } 3.3 \mbox{ V with} \\ V_{NO} \mbox{ floating} \\ V_{COM} = 0.3 \mbox{ V or } 3.3 \mbox{ V} \end{array} $	3.6	-10	10	-100	100	nA

7. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

8. Flatness is defined as the difference between the maximum and minimum value of On-resistance as measured over the specified analog signal ranges.

9.  $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$  between NC1 and NC2 or between NO1 and NO2.

## AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$ )

					0	Suaran	teed M	aximum L	.imit						
			V		V	V.s. V.s	Vee Vee	Vee Vee	V <sub>CC</sub> V <sub>IS</sub>	25°C			–40°C to +85°C		
Symbol	Parameter	Test Conditions	(V)	(V)	Min	Тур*	Max	Min	Max	Unit					
t <sub>ON</sub>	Turn–On Time	$R_L = 50 \Omega$ , $C_L = 35 pF$ (Figures 3 and 4)	2.3 – 3.6	1.5			50		60	ns					
t <sub>OFF</sub>	Turn–Off Time	$R_L = 50 \Omega$ , $C_L = 35 pF$ (Figures 3 and 4)	2.3 – 3.6	1.5			30		40	ns					
t <sub>BBM</sub>	Minimum Break–Before–Make Time	$V_{IS} = 3.0$ $R_{L} = 50 \ \Omega$ , $C_{L} = 35 \ pF$ (Figure 2)	3.0	1.5	2	15				ns					

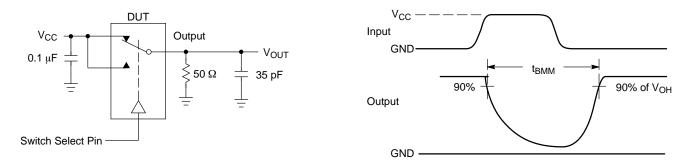
		Typical @ 25, V <sub>CC</sub> = 3.6 V	
C <sub>IN</sub>	Control Pin Input Capacitance	3.5	pF
C <sub>NO/NC</sub>	NO, NC Port Capacitance	75	pF
C <sub>COM</sub>	COM Port Capacitance When Switch is Enabled	240	pF

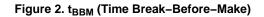
\*Typical Characteristics are at 25°C.

## ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

			V <sub>CC</sub>	25°C	
Symbol	Parameter	Condition	(V)	Typical	Unit
BW	Maximum On–Channel –3 dB Bandwidth or Minimum Frequency Response	$V_{\text{IN}}$ centered between $V_{\text{CC}}$ and GND (Figure 5)	1.65 – 3.6	17	MHz
V <sub>ONL</sub>	Maximum Feed-through On Loss	$V_{IN}$ = 0 dBm @ 100 kHz to 50 MHz $V_{IN}$ centered between $V_{CC}$ and GND (Figure 5)	1.65 – 3.6	-0.06	dB
V <sub>ISO</sub>	Off-Channel Isolation	f = 100 kHz; $V_{IS}$ = 1 V RMS; $C_L$ = 5.0 pF $V_{IN}$ centered between $V_{CC}$ and GND (Figure 5)	1.65 – 3.6	-65	dB
Q	Charge Injection Select Input to Common I/O	$V_{IN} = V_{CC to} \text{ GND}, R_{IS} = 0 \text{ W}, C_L = 1.0 \text{ nF}$ Q = C <sub>L</sub> x DV <sub>OUT</sub> (Figure 6)	1.65 – 3.6	38	рС
THD	Total Harmonic Distortion THD + Noise	$\rm F_{IS}$ = 20 Hz to 20 kHz, $\rm R_{L}$ = $\rm R_{gen}$ = 600 $\Omega,$ $\rm C_{L}$ = 50 pF $\rm V_{IS}$ = 2.0 V RMS	3.0	0.12	%
VCT	Channel-to-Channel Crosstalk	f = 100 kHz; $V_{IS}$ = 1.0 V RMS, $C_L$ = 5.0 pF, $R_L$ = 50 $\Omega$ V <sub>IN</sub> centered between V <sub>CC</sub> and GND (Figure 5)	1.65 – 3.6	-70	dB

10. Off-Channel Isolation = 20log10 ( $V_{COM}/V_{NO}$ ),  $V_{COM}$  = output,  $V_{NO}$  = input to off switch.





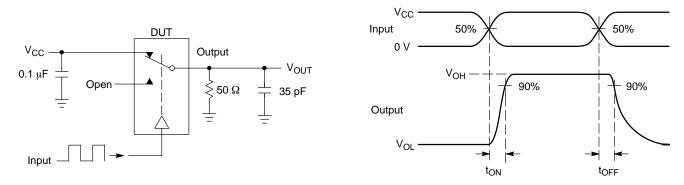
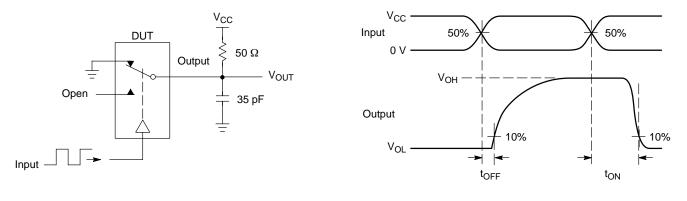
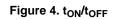
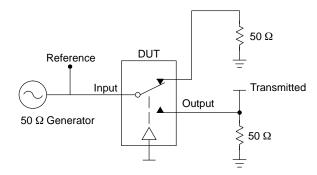


Figure 3. t<sub>ON</sub>/t<sub>OFF</sub>



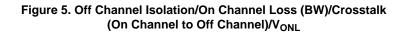




Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch.  $V_{ISO}$ , Bandwidth and  $V_{ONL}$  are independent of the input signal direction.

$$\begin{split} & \mathsf{V}_{\mathsf{ISO}} = \mathsf{Off \ Channel \ Isolation} = 20 \ \mathsf{Log} \, \left( \frac{\mathsf{V}_\mathsf{OUT}}{\mathsf{V}_\mathsf{IN}} \right) \ \text{for} \ \mathsf{V}_\mathsf{IN} \ \text{at} \ 100 \ \mathsf{kHz} \\ & \mathsf{V}_\mathsf{ONL} = \mathsf{On \ Channel \ Loss} = 20 \ \mathsf{Log} \, \left( \frac{\mathsf{V}_\mathsf{OUT}}{\mathsf{V}_\mathsf{IN}} \right) \ \text{for} \ \mathsf{V}_\mathsf{IN} \ \text{at} \ 100 \ \mathsf{kHz} \ \text{to} \ 50 \ \mathsf{MHz} \end{split}$$

Bandwidth (BW) = the frequency 3 dB below V<sub>ONL</sub> V<sub>CT</sub> = Use V<sub>ISO</sub> setup and test to all other switch analog input/outputs terminated with 50  $\Omega$ 



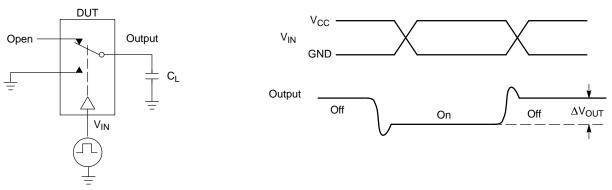
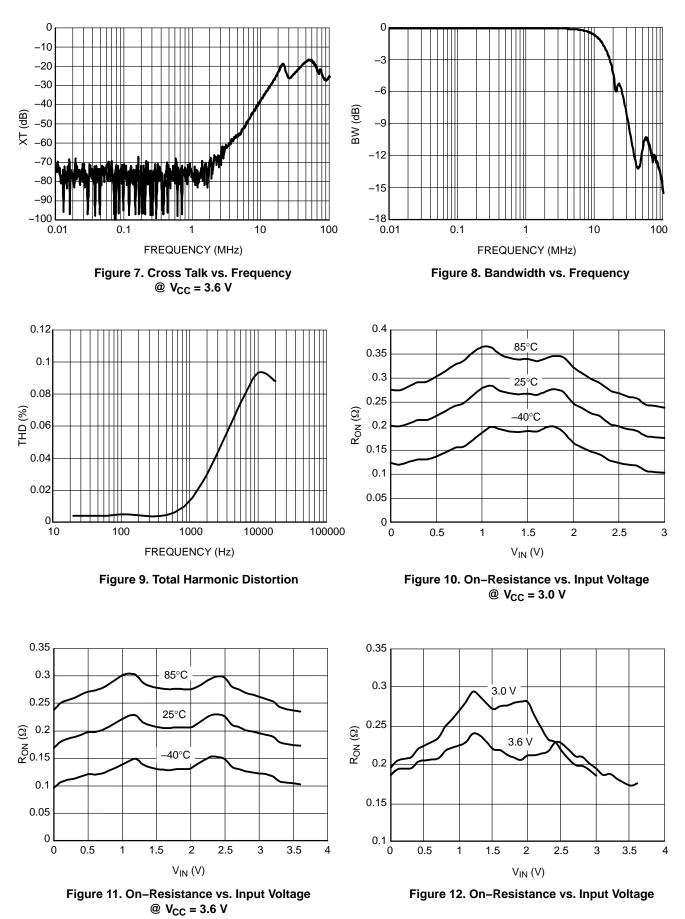


Figure 6. Charge Injection: (Q)

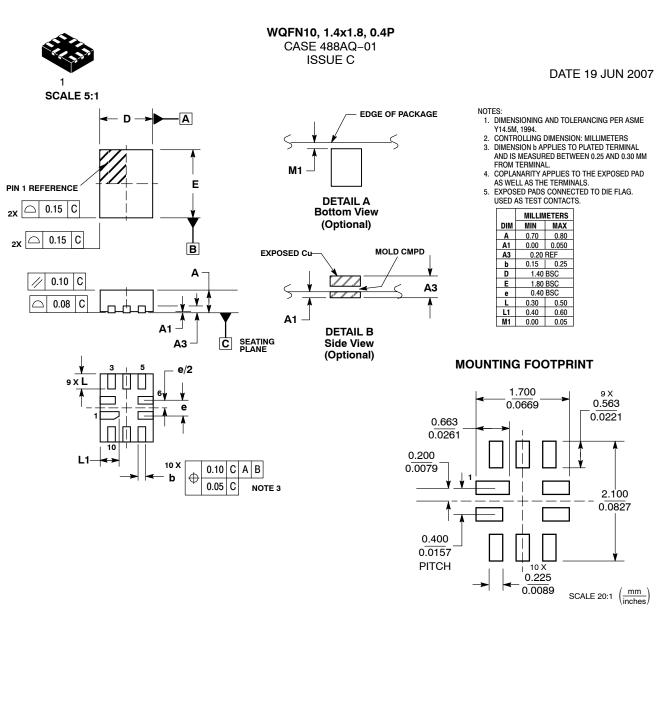


#### **ORDERING INFORMATION**

Device	Package	Shipping†
NLAS5223MNR2G	WQFN-10 (Pb-Free)	3000 / Tape & Reel
NLAS5223LMNR2G	WQFN-10 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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DESCRIPTION:	WQFN10, 1.4 X 1.8, 0.4P		PAGE 1 OF 1
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